

# ATLAS Beam Condition Monitor

## Working principle

Distinguish interactions from background via time of flight

With two symmetric stations at  $\pm\Delta z/2$

Interactions: in time

Background: out of time on one side by  $\Delta t = \Delta z/c$

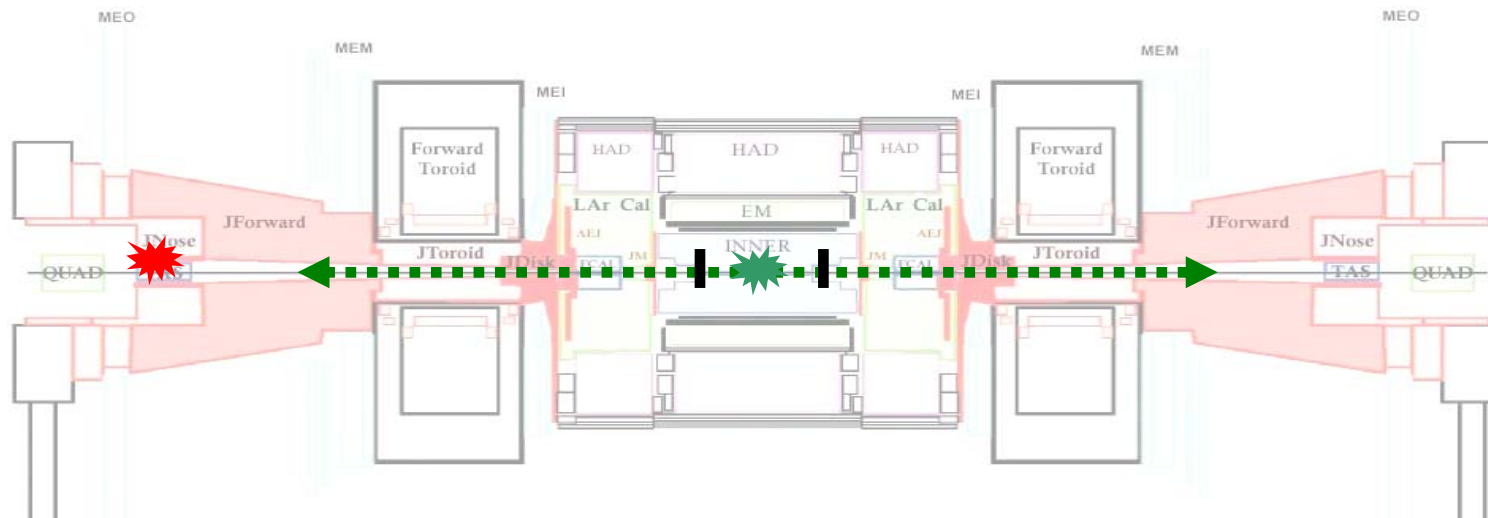
At high luminosity expect about one hit for each bunch crossing

Interactions at  $\Delta t = 0, 25, 50 \dots$  ns

Optimally distinguished background at  $\Delta t = 12.5$  ns  $\Rightarrow$

$\Delta z = 3.8$  m





## Sensors

### Polycrystalline CVD diamond sensors chosen

Radiation hard – shown to work at  $> 10^{15}$  particles/cm<sup>2</sup>

Fast signals – high velocity and cut-off due to trapping

Small leakage current – no cooling required

### Procurement in collaboration with CERN RD-42

Sensors produced and conditioned by Element Six Ltd.

Metallized with proprietary radiation hard process at OSU

### Sensor properties

Size 10 mm x10 mm, active 8 mm x 8 mm (metallization)

Thickness ~500  $\mu$ m

Charge collection distance ~220  $\mu$ m

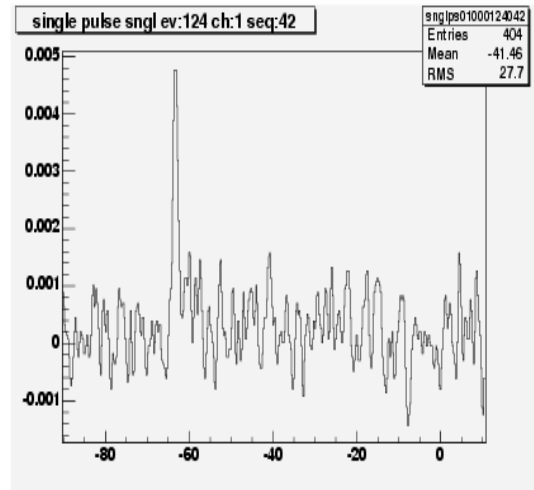
Holds ~ 2 V/  $\mu$ m, operating voltage 1000 V, current ~ nA



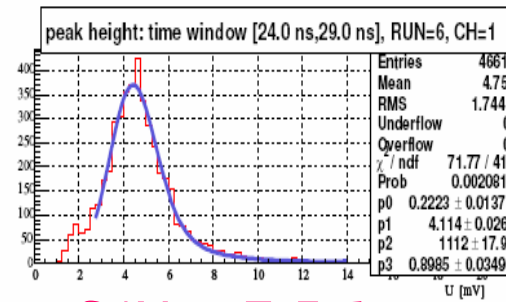
# Measurements with $\beta$ source:

Fotec FE (500 MHz)

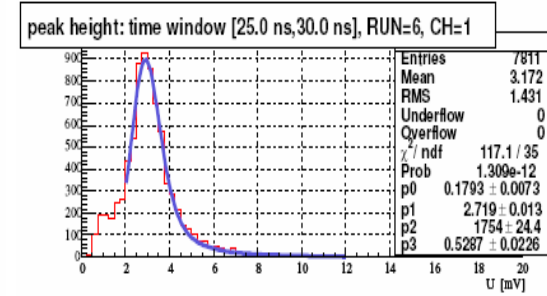
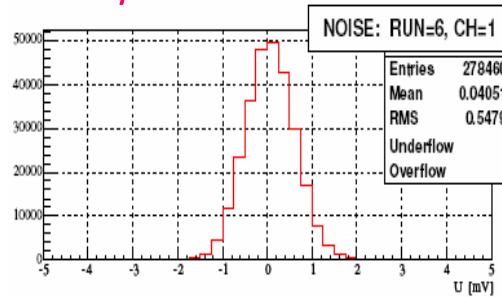
200 MHz BWL



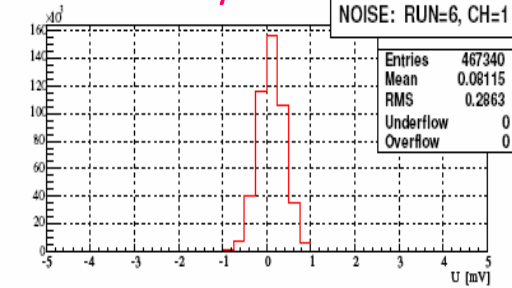
Typical MIP pulse



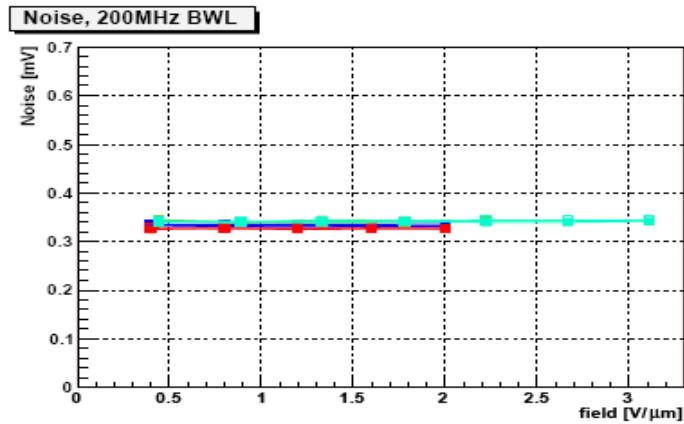
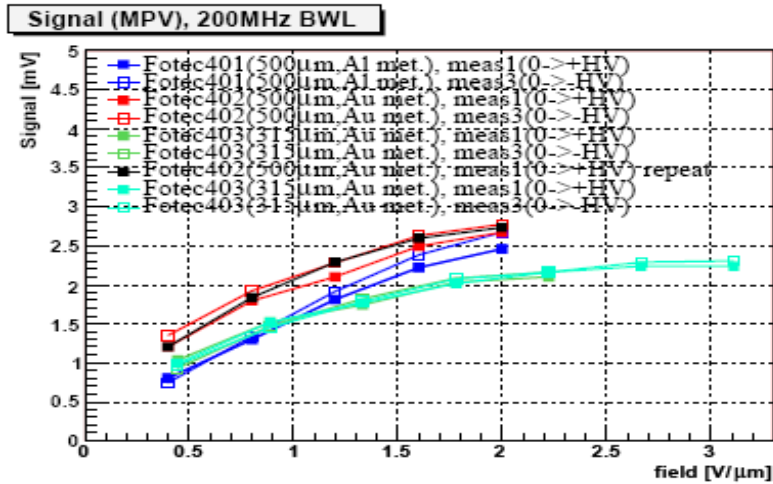
S/N ~ 7.5:1



S/N ~ 9.2:1



# Measurements with $\beta$ source:



## NINO amplifier-discriminator tests

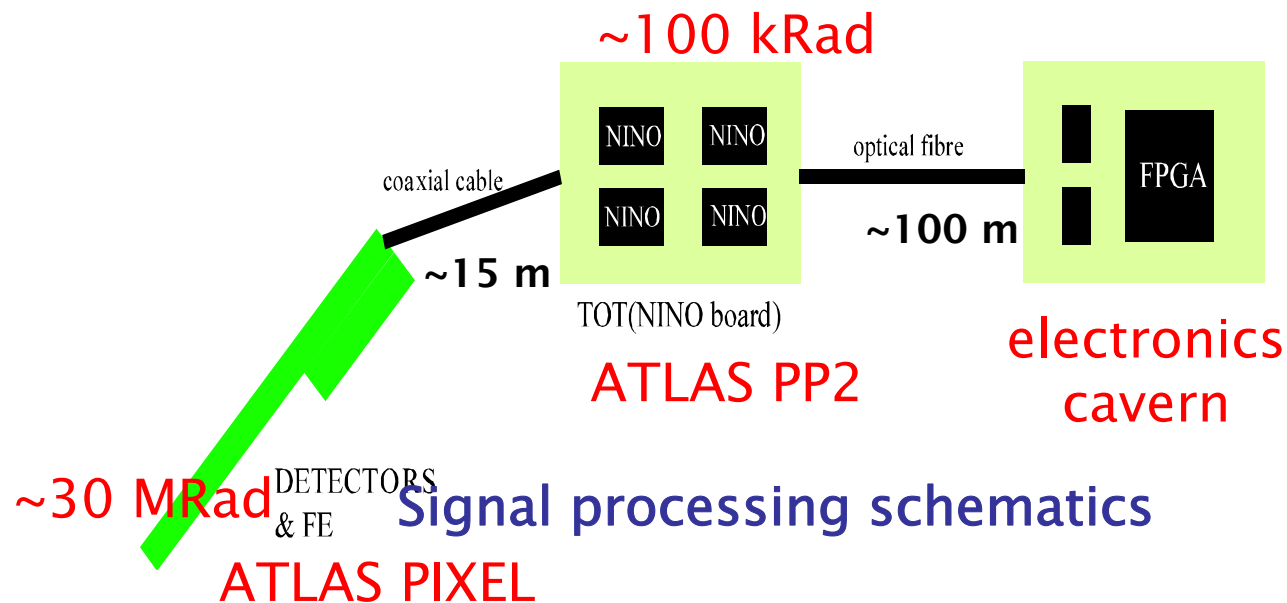
Differential timing amplifier-discriminator (1 ns peak, 25 ns jitter)

LVDS output with width proportional to time-over-threshold

Radiation tolerant design by CERN-MIC

Signal split 1:12 into two inputs to increase dynamic range

Tests confirm suitability as **BCM** back-end chip



# Production status:

- 8 module boxes completed, equipped with sensors
- 2 spare boxes in production
- brackets produced
- 2 prototype NINO boards produced, measurements in beamtest running
- beamtest with microstrip telescope underway







